### 2.5V Drive Nch+Nch MOS FET

## UM6K1N

## - Structure

Silicon N-channel MOS FET

## -Features

1) Two 2 SK3018 transistors in a single UMT package.
2) The MOS FET elements are independent, eliminating mutual interference.
3) Mounting cost and area can be cut in half.
4) Low On-resistance.
5) Low voltage drive ( 2.5 V drive) makes this device ideal for portable equipment.

## - Applications

Interfacing, switching (30V, 100mA)

## -Packaging specifications

| Type | Package | Taping |
| :--- | :--- | :---: |
|  | Code | TN |
|  | Basic ordering unit (pieces) | 3000 |
| UM6K1N |  |  |

- Absolute maximum ratings $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$
<lt is the same ratings for Tr1 and Tr2.>

| Parameter |  | Symbol | Limits | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Drain-source voltage | V $_{\text {DSS }}$ | 30 | V |  |
| Gate-source voltage | VGSS | $\pm 20$ | V |  |
| Drain current | Continuous | $\mathrm{ID}_{\mathrm{D}}$ | $\pm 100$ | mA |
|  | Pulsed | $\mathrm{IDP}^{* 1}$ | $\pm 400$ | mA |
| Total power dissipation | $\mathrm{PD}^{* 2}$ | 150 | mW |  |
| Channel temperature | Tch | 150 | ${ }^{\circ} \mathrm{C}$ |  |
| Range of storage temperature | Tstg | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |  |

*1 Pw $\leq 10 \mu \mathrm{~s}$, Duty cycle $\leq 1 \%$
*2 With each pin mounted on the recommended lands.

## - Thermal resistance

| Parameter | Symbol | Limits | Unit |
| :--- | :---: | :---: | :---: |
| Channel to ambient | Rth(ch-a) ${ }^{*}$ | 833 | ${ }^{\circ} \mathrm{C} / \mathrm{W} / \mathrm{TOTAL}$ |
|  |  | 1042 | ${ }^{\circ} \mathrm{C} / \mathrm{W} / \mathrm{ELEMENT}$ |

[^0]-External dimensions (Unit : mm)
UMT6


Each lead has same dimensions
Abbreviated symbol : K1

(1) Tr1 Source $*$ A protection diode has been built (2) Tr1 Gate in between the gate and the source (3) Tr 2 Drain to protect against static electricity (4) Tr2 Source when the product is in use. $\begin{array}{ll}\text { (5) Tr2 Gate } & \text { Use the protection circuit when } \\ \text { (6) Tr1 Drain } & \text { rated voltages are exceeded. }\end{array}$ rated voltages are exceeded.


Transistors
-Electrical characteristics $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$
<lt is the same characteristics for Tr1 and Tr2.>

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Gate-source leakage | Igss | - | - | $\pm 1$ | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{GS}}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\text {ds }}=0 \mathrm{~V}$ |
| Drain-source breakdown voltage | $V_{\text {(BR) }}$ DSS | 30 | - | - | V | $\mathrm{ld}=10 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ |
| Zero gate voltage drain current | Idss | - | - | 1.0 | $\mu \mathrm{A}$ | V ${ }_{\text {ds }}=30 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ |
| Gate threshold voltage | $\mathrm{V}_{\mathrm{GS}}$ (th) | 0.8 | - | 1.5 | V | $V_{D S}=3 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=100 \mu \mathrm{~A}$ |
| Static drain-source on-state resistance | Rds (on) | - | 5 | 8 | $\Omega$ | $\mathrm{ID}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=4 \mathrm{~V}$ |
|  |  | - | 7 | 13 | $\Omega$ | $\mathrm{ld}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=2.5 \mathrm{~V}$ |
| Forward transfer admittance | $\left\|Y_{f s}\right\|$ | 20 | - | - | mS | $\mathrm{I}_{\mathrm{D}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{DS}}=3 \mathrm{~V}$ |
| Input capacitance | Ciss | - | 13 | - | pF | $\begin{aligned} & V_{D S}=5 \mathrm{~V} \\ & V_{G S}=0 \mathrm{~V} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ |
| Output capacitance | Coss | - | 9 | - | pF |  |
| Reverse transfer capacitance | Crss | - | 4 | - | pF |  |
| Turn-on delay time | td (on) | - | 15 | - | ns | $\begin{aligned} & \mathrm{VDD} \fallingdotseq 5 \mathrm{~V} \\ & \mathrm{ID}=10 \mathrm{~mA} \\ & \mathrm{VGS}=5 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=500 \Omega \\ & \mathrm{RG}=10 \Omega \\ & \hline \end{aligned}$ |
| Rise time | tr | - | 35 | - | ns |  |
| Turn-off delay time | $t_{d}$ (off) | - | 80 | - | ns |  |
| Fall time | $\mathrm{t}_{\mathrm{f}}$ | - | 80 | - | ns |  |

## - Electrical characteristic curves



Fig. 1 Typical Output Characteristics


Fig. 4 Static Drain-Source On-State Resistance vs. Drain Current ( I)


Fig. 2 Typical Transfer Characteristics


Fig. 5 Static Drain-Source On-State Resistance vs. Drain Current (II)


Fig. 3 Gate Threshold Voltage vs. Channel Temperature


Fig. 6 Static Drain-Source On-State Resistance vs. Gate-Source Voltage


## -Switching characteristics measurement circuit



Fig. 13 Switching Time Test Circuit


Fig. 14 Switching Time Waveforms

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[^0]:    * With each pin mounted on the recommended lands.

